

Features

- High-speed switching
- Drive circuits can be simple
- Parallel use is easy
- HBM: AEC-Q101-001: H1A (JESD22-A114-B: 1A)
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

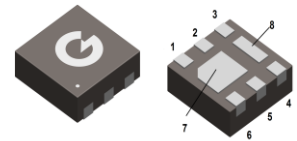
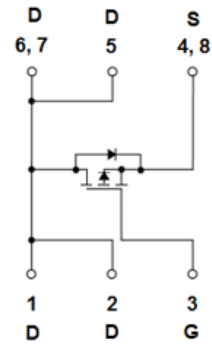
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Typical Applications

- Power management in note book
- Switching application
- Battery powered system
- Load switch

Mechanical Data

- Case: DFN2020-6L
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals: Matte tin-plated leads; solderability-per MIL-STD-202, Method 208



DFN2020-6L

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TBL3415DF1	DFN2020-6L	3000 pcs / Tape & Reel	3415

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	-20	V
Gate-to-Source Voltage	V _{GSS}	±12	V
Continuous Drain Current (T _C = 25°C)	I _D	-11	A
Continuous Drain Current (T _A = 25°C) *1		-5.5	
Continuous Drain Current (T _A = 70°C) *1		-4.4	
Pulsed Drain Current (t _p = 10μs, T _A = 25°C)	I _{DM}	-30	A
Single Pulse Avalanche Energy *3	E _{AS}	5.5	mJ
Power Dissipation (T _C = 25°C)	P _D	8.3	W
Power Dissipation (T _A = 25°C) *1		1.9	
Operating Junction Temperature Range	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Thermal Characteristics

Parameter	Symbol	Min.	Typ.	Max.	Unit
Thermal Resistance Junction-to-Case	$R_{\theta JC}$	-	-	15	$^{\circ}\text{C/W}$
Thermal Resistance Junction-to-Air ^{*1}	$R_{\theta JA}$	-	60	65	$^{\circ}\text{C/W}$

Electrical Characteristics (@ $T_A = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
Static Characteristics						
V _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0V, I _D = -250μA	-20	-	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = -20V, V _{GS} = 0V	-	-	-1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±12V, V _{DS} = 0V	-	-	±100	nA
On Characteristics						
R _{DS(ON)}	Drain-Source On-resistance *2	V _{GS} = -4.5V, I _D = -4A	-	-	50	mΩ
		V _{GS} = -2.5V, I _D = -4A	-	-	70	
		V _{GS} = -1.8V, I _D = -1A	-	-	100	
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} = V _{GS} , I _D = -250uA	-0.3	-0.75	-1.0	V
R _G	Gate Resistance	V _{GS} = 0V, f = 1MHz	-	29	-	Ω
Dynamic Characteristics						
C _{ISS}	Input Capacitance	V _{GS} = 0V V _{DS} = -10V f = 1.0MHz	-	977	-	pF
C _{OSS}	Output Capacitance		-	109	-	
C _{RSS}	Reverse Transfer Capacitance		-	92	-	
Switching Characteristics						
t _{d(ON)}	Turn-on Delay Time *4	V _{DD} = -10V V _{GS} = -4.5V R _G = 3Ω R _L = 2.5Ω	-	9.5	-	ns
t _r	Turn-on Rise Time *4		-	17	-	
t _{d(OFF)}	Turn-Off Delay Time *4		-	94	-	
t _f	Turn-Off Fall Time *4		-	35	-	
Q _G	Total Gate-Charge	V _{DD} = -10V V _{GS} = -4.5V I _D = -4A	-	10	-	nC
Q _{GS}	Gate to Source Charge		-	2.3	-	
Q _{GD}	Gate to Drain (Miller) Charge		-	2	-	
Source-Drain Diode Characteristics						
V _{SD}	Diode Forward Voltage *2	I _{SD} = -1A,V _{GS} = 0V	-	-0.7	-1	V

Notes:

- The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper
- The data tested by pulsed, pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$
- The E_{AS} data shows Max. rating. The test condition is $V_{DD} = -10\text{V}$, $V_{GS} = -6\text{V}$, $L = 0.1\text{mH}$
- Guaranteed by design, not subject to production

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

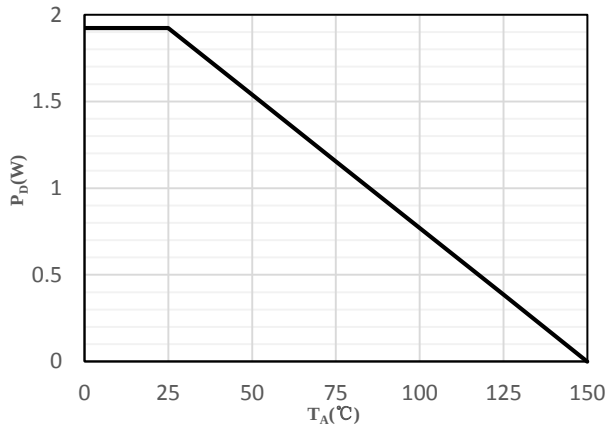


Fig 1 Power Dissipation

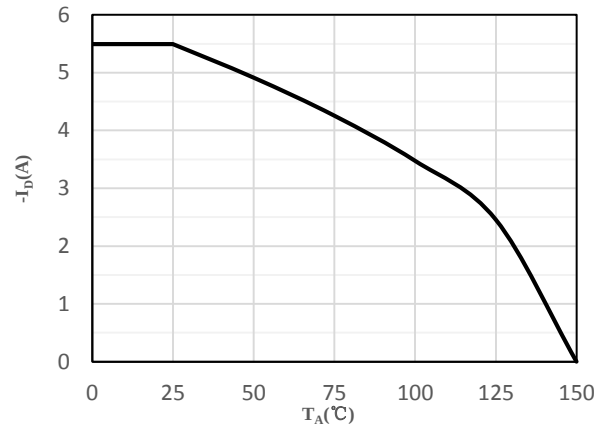


Fig 2 Drain Current

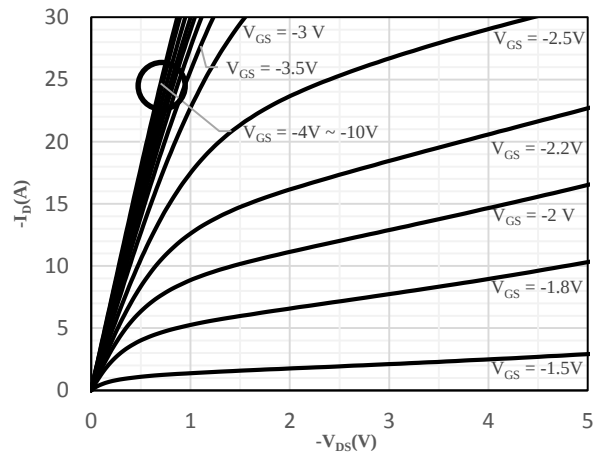


Fig 3 Typical Output Characteristics

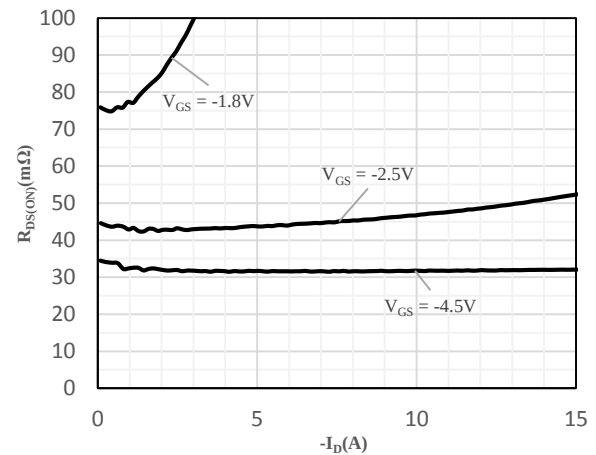


Fig 4 On-Resistance vs. Drain Current
and Gate Voltage

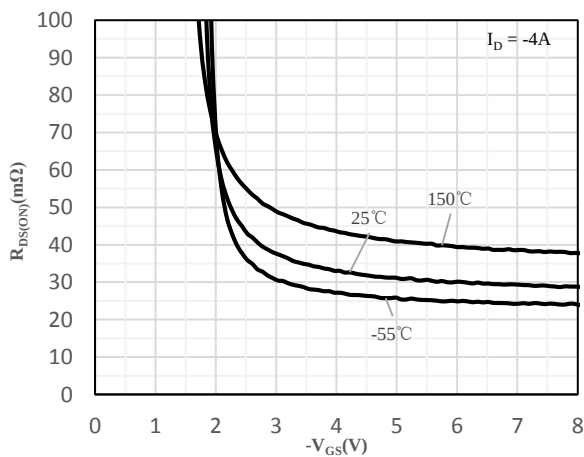


Fig 5 On-Resistance vs. Gate-Source Voltage

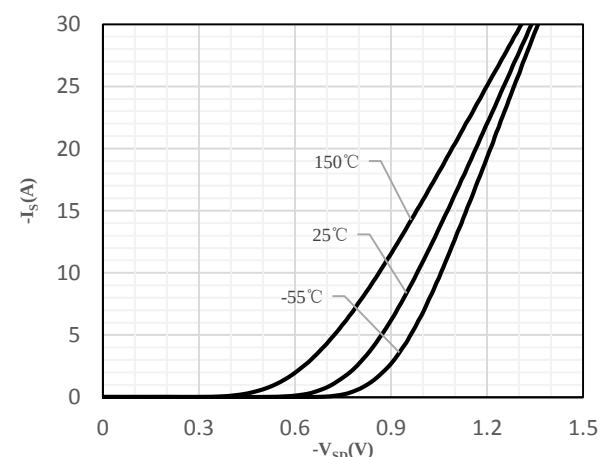


Fig 6 Body-Diode Characteristics

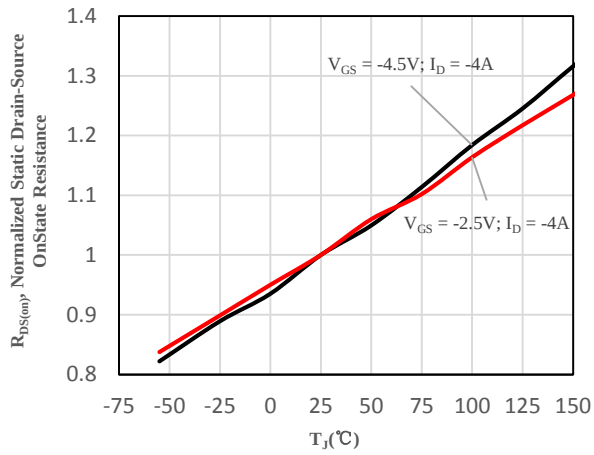


Fig 7 Normalized On-Resistance vs. Junction Temperature

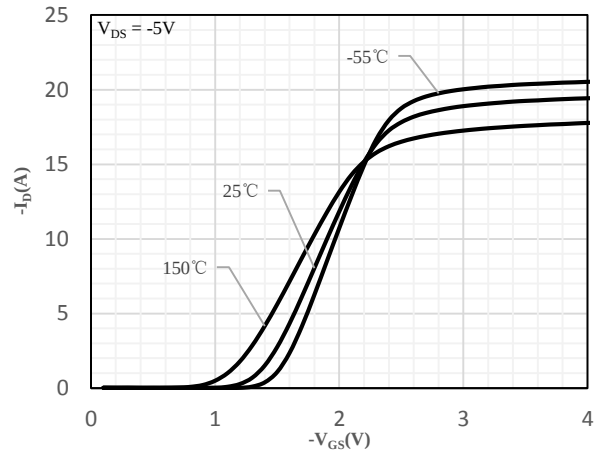


Fig 8 Transfer Characteristics

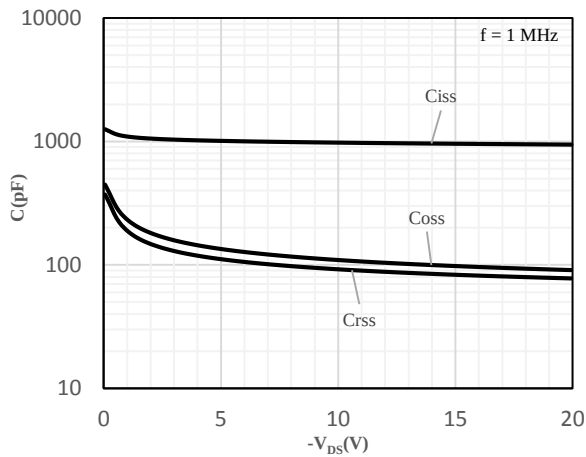


Fig 9 Capacitance Characteristics

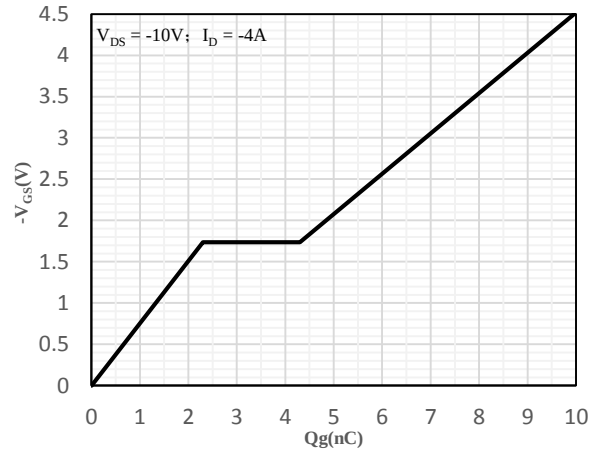


Fig 10 Gate-Charge Characteristics

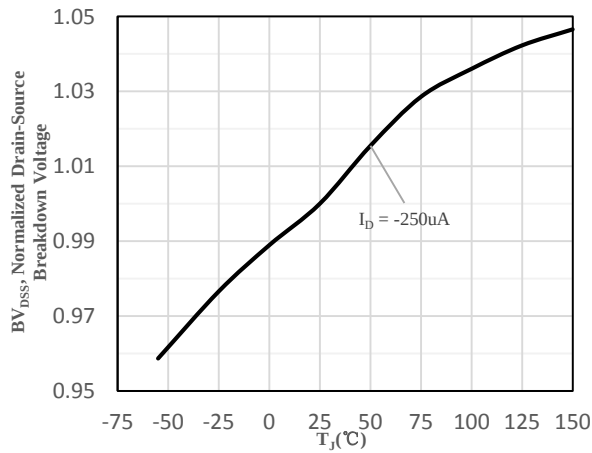


Fig 11 Normalized Breakdown Voltage vs. Junction Temperature

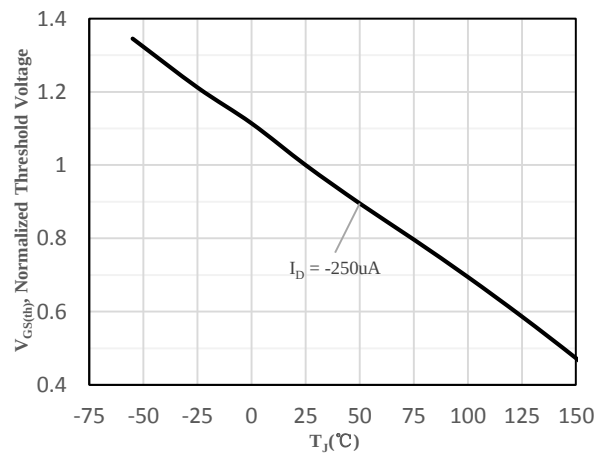
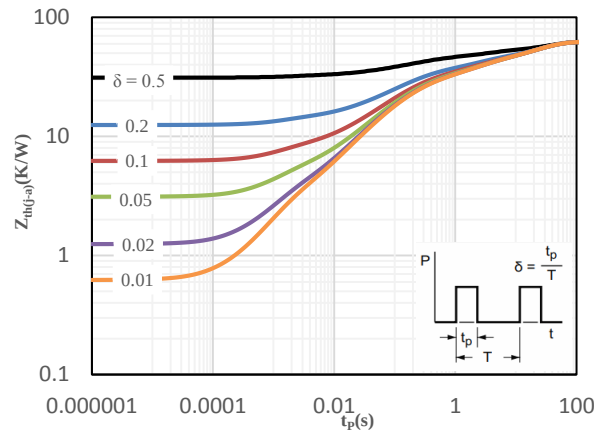
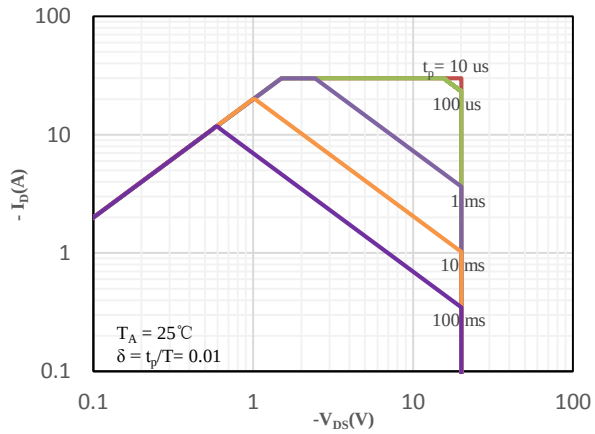
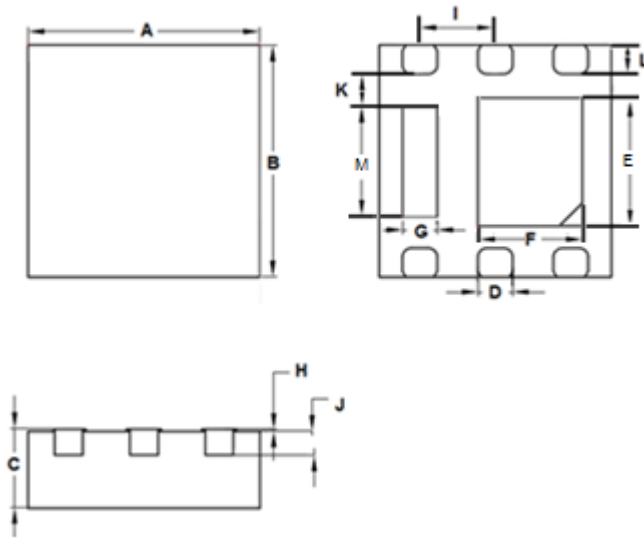


Fig 12 Normalized $V_{GS(th)}$ vs. Junction Temperature



Package Outline Dimensions (Unit: mm)



DFN2020-6L		
Dimension	Min.	Max.
A	1.924	2.076
B	1.924	2.076
C	0.500	0.600
D	0.250	0.350
E	0.900	1.100
F	0.850	1.050
G	0.200	0.400
H	0.000	0.050
I	0.550	0.750
J	0.103	0.303
K	0.150	0.350
L	0.200	0.400
M	0.700	0.900

Mounting Pad Layout (Unit: mm)

DFN2020-6L

